King Fahd University of Petroleum & Minerals Electrical Engineering Department EE203: Electronics I (061)

Instructor	Dr Sheikh	0.65 14.005		T 1 2010		Email:		Office Hours: SMW → 9:05 to 9:45 AM						
Information	Sharif Iqbal	Office	Office: 14-225		Tel: 2818		Sheikhsi@kfupm.edu.sa			UT → 11:05 to 11:00 AM or by appointments				
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Course	Text Microelectronic Circ	mite 5th od	IIW/+O:		Dunings		Grading T E	T als	Eira	nal Exa		Attendance		
Information	Sedra & Smith		HW+Quizzes						FIII	131 Exa		6 unexcused absences → Warning 9 unexcused absences → DN		
	Sedia & Sili		1370		370		3070	20 / 0		3070	70 9 unexcused absences →		→ D N	
Week	Events				Topics to	о со	ver			Ch	Sections	Lab Activity	Exercises	
Week 1	Normal Saturday	Diodes: Introduction, Ideal diode, PN junction, Terminal characteristics of the diode,						le,	3	1, 2, 7	No Lab	(3) 3, 10, 11, 26		
Sept 9–14	Classes On Sept 14	Physical operation of the diode.											, ,	
Week 2 Sept 16-20	Last day to drop without W Sept 19	Graphical and analytical diode circuits analysis, Diode Models, the Zener diode.							3	3.1-3.3, 3.5, 3.6, 4.1, 4.2	Exp 1: Lab Equipment	40, 68, 72, 95, 104		
Week 3	National Holiday	Diode appli	Diode applications: half and Full-wave rectifiers, Limiting and Clamping circuits and						ınd	3	5.1-5.4, 6	Exp 2: Pspice	101	
Sept 24-27	Sept 23		voltage doublers. Field-Effect Transistors (FETs): Device structure and operation.						ina	4	1.1-1.5	Introduction		
Week 4							Current –Voltage			4	1.6-1.8, 2.1-	Exp 3: Diode	(4) 38, 42, 46	
Sept 30-Oct 4					rcuits at DC.					4	2.5, 3	Applications		
Week 5			IOSFET as amplifier, Biasing, small signal operation and models, Single stage						4	4-7	Exp 4: DC Power	52,74, 75, 81		
Oct 7-11		amplifier (C	CS, CG and	CD).						•	 -/	Supply	52,74,75,01	
	tion Oct 14-Oct 28													
Week 6 Oct 28-Nov 1	Midterm reports to Registrar Oct 31	Single stage	e amplifier (Continu	ed) (CS, CG	& C	D).			4	7	No Lab	82, 85,87	
Week 7	Exam 1 Sat Nov 4	Bipolar Jun	ction Transi	stors (B	JTs): structur	e an	d operation, types.	symbols and		5	1.1-1.3, 1.5,	Exp 5: MOSFET	(5) 7, 21, 24, 39,	
Nov 4-8	5:30-7:30 pm	conventions	conventions, transistors current-voltage characteristics.							5	1.6, 2, 3	Amplifiers	57, 58, 66	
Week 8 Nov 11-15		BJT circuit	BJT circuits at DC, Biasing, Small signal models and analysis.						5	4-6	No Lab	72, 74, 80, 84 (b), 89, 112, 116		
Week 9 Nov 18-22		Single stage amplifier (CE, CB, and CC).						5	7	Exp 6: BJT Characteristics	124, 130, 136, 141, 143, 144			
Week 10 Nov 25-29	Last day to drop all courses Nov 29	Differential Amplifiers: MOS and BJT Differential amplifiers.				ial amplifiers.			7	1-3	Exp 7: BJT CE Amplifiers	(7) 1, 2, 14, 15, 40		
Week 11 Dec 2-6	Early registration for 062 starts Dec 2	Digital Circ	cuit design o	gn overview, the CMOS inverter.				10	1.1, 1.2, 2.1, 2.2	No Lab				
Week 12	101 002 statts Dec 2		Logic circuits, CMOS transistor sizing.									Exp 8: Differential	(10) 25, 26, 32,	
Dec 9-13		CMOS Log								10	3.1-3.8	Amp.	34, 50	
Week 13	Exam 2 Wed Dec20			logic circuits (PTL), Basic concept of dynamic logic circuits. BJT as a				s a	10	4.1, 4.2, 5,6.1	Exp 9: CMOS			
Dec 16-20	5:30-7:30 pm	switch, The basic BJT inverter.							5	3.4, 10	Inverter			
	acation Dec 23-Jan 3								1	1		T	1	
14	Last day for WP	RTL circuits, maximum fan-out calculation, TTL Basic Inverters and NAND gate,						11	7.1, 7.3	Exp 10: ECL Logic	(11) 40			
Jan 6-10 15	/WF drop Jan 10	ECL logic of	circuits.								Handout	Gates	` ′	
15 Jan 13-17	Last day of classes Jan 17	ECL logic o	circuits (con	t.), BJT	vs. MOS Log	gic: a	advantage/disadva	ntages.		11	7.4, 7.7 Handout	Lab Final		
Jan 13-17	Jan 17										Tanuout			